Technische Information / Technical Information

eupec

Netz-Thyristor
Phase Control Thyristor

T 378 N 12...16

N

Elektrische Eigenschften / Electrical properties

Höchstzulässige Werte / Maximum rated values

Periodische Vorwärts- und Rückwärts-Spitzensperrspannung repetitive peak forward off-state and reverse voltages	T_{vj} = - 40°C...$T_{vj\,max}$	V_{DRM} , V_{RRM}	1200, 1400 1600	V V
Vorwärts-Stoßspitzensperrspannung non-repetitive peak foward off-state voltage	T_{vj} = - 40°C...$T_{vj\,max}$	V_{DSM}	1200, 1400 1600	V V
Rückwärts-Stoßspitzensperrspannung non-repetitive peak reverse voltage	T_{vj} = + 25°C...$T_{vj\,max}$	V_{RSM}	1300, 1500 1700	V V
Durchlaßstrom-Grenzeffektivwert RMSM on-state current		I_{TRSMSM}	800	A
Dauergrenzstrom average on-state current	T_C = 85 °C T_C = 65 °C	I_{TAVM}	378 510	A A
Stoßstrom-Grenzwert surge current	T_{vj} = 25°C, t_p = 10 ms T_{vj} = $T_{vj\,max}$, t_p = 10 ms	I_{TSM}	7100 6350	A A
Grenzlastintegral I²t-value	T_{vj} = 25°C, t_p = 10ms T_{vj} = $T_{vj\,max}$, t_p = 10ms	I²t	252 202	A²s*10³ A²s*10³
Kritische Stromsteilheit critical rate of rise of on-state current	DIN IEC 747-6 f=50 Hz, v_L = 10V, i_{GM} = 1 A di_G/dt = 1 A/µs	$(di_T/dt)_{cr}$	150	A/µs
Kritische Spannungssteilheit critical rate of rise of off-state voltage	T_{vj} = $T_{vj\,max}$, v_D = 0,67 V_{DRM} 5.Kennbuchstabe / 5th letter F	$(dv_D/dt)_{cr}$	1000	V/µs

Charakteristische Werte / Characteristic values

Durchlaßspannung on-state voltage	T_{vj} = $T_{vj\,max}$, i_T = 1200 A T_{vj} = $T_{vj\,max}$, i_T = 300 A	v_T	max. 1,85 max. 1,10	V V
Schleusenspannung threshold voltage	T_{vj} = $T_{vj\,max}$	$V_{T(TO)}$	0,8	V
Ersatzwiderstand slope resistance	T_{vj} = $T_{vj\,max}$	r_T	0,75	mΩ
Durchlaßkennlinie on-state voltage $v_T = A + B \times i_T + C \times \ln(i_T + 1) + D \times \sqrt{i_T}$	T_{vj} = $T_{vj\,max}$	A=0,98647 B=2,62244E-04 C=-0,1155492 D=3,953E-02		
Zündstrom gate trigger current	T_{vj} = 25°C, v_D = 6 V	I_{GT}	max. 200	mA
Zündspannung gate trigger voltage	T_{vj} = 25°C, v_D = 6V	V_{GT}	max. 2,0	V
Nicht zündener Steuerstrom gate non-trigger current	T_{vj} = $T_{vj\,max}$, v_D = 6 V T_{vj} = $T_{vj\,max}$,v_D = 0,5 V_{DRM}	I_{GD}	max. 10 max. 5	mA mA
Nicht zündene Steuerspannung gate non-trigger voltage	T_{vj} = $T_{vj\,max}$,v_D = 0,5 V_{DRM}	V_{GD}	max. 0,2	mV
Haltestrom holding current	T_{vj} = 25°C, v_D = 6 V, R_A = 5 Ω	I_H	max. 300	mA
Einraststrom latching current	T_{vj} = 25°C, v_D = 6 V, R_{GK}>=10 Ω i_{GM} = 1 A, di_G/dt = 1 A/µs t_g = 20 µs	I_L	max. 1200	mA
Vorwärts- und Rückwärts-Sperrstrom forward off-state and reverse currents	T_{vj} = $T_{vj\,max}$ v_D = V_{DRM}, v_R = V_{RRM}	i_D, i_R	max. 50	mA
Zündverzug gate controlled delay time	DIN IEC 747-6 T_{vj} = 25°C i_{GM} = 1 A, di_G/dt = 1 A/µs	t_{gd}	max. 3	µs

Elektrische Eigenschften / Electrical properties

Charakteristische Werte / Characteristic values

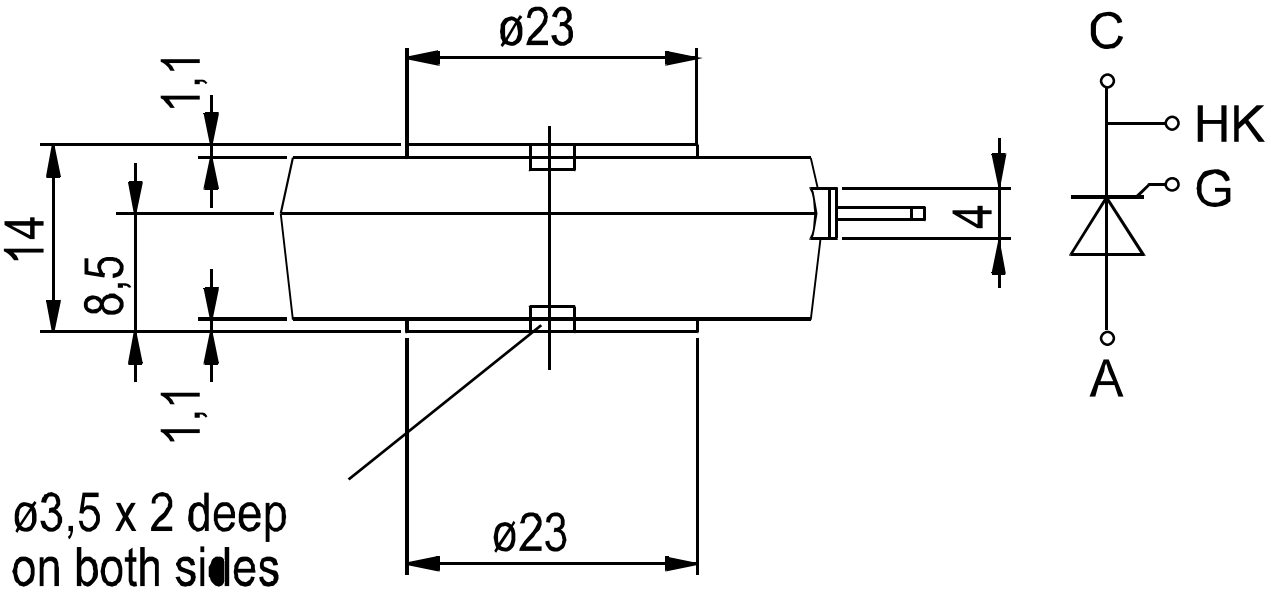
Freiwerdezeit circuit commutatet turn-off time	$T_{vj} = T_{vj\,max}$, $i_{TM}=I_{TAVM}$ v_{RM} =100V, v_{DM} = 0,67 V_{DRM} dv_D/dt = 20 V/µs, $-di_T/dt$ = 10 A/µs 4. Kennbuchstabe / 4th letter O	t_q	typ. 250	µs

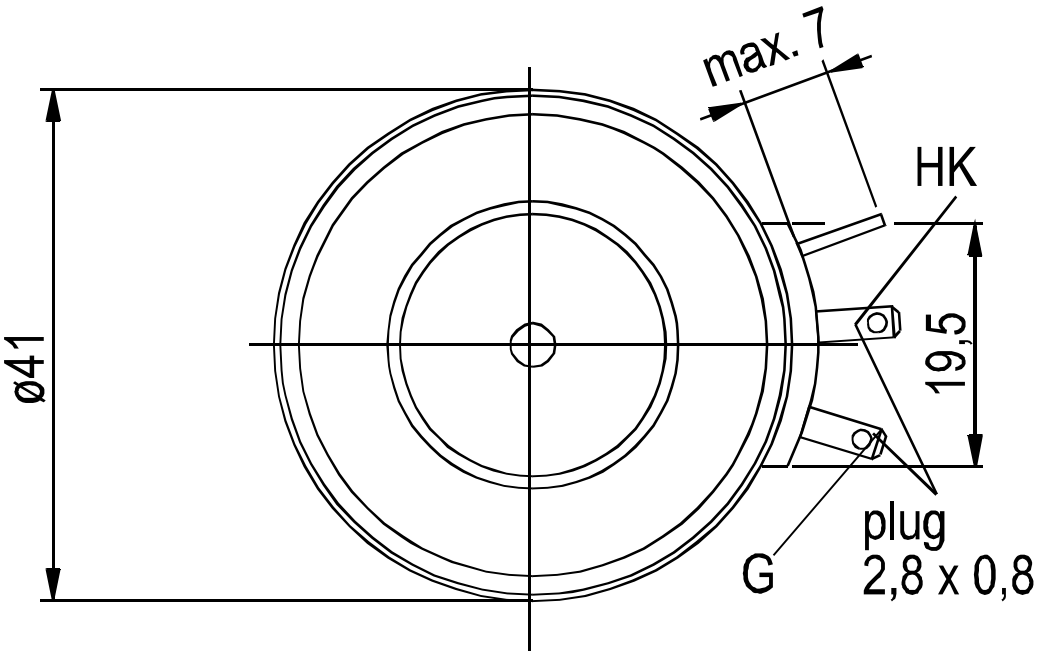
Thermische Eigenschaften / Thermal properties

Innerer Wärmewiderstand thermal resitance, junction to case	Kühlfläche / cooling surface beidseitig / two-sided, Θ=180°sin beidseitig / two-sided, DC Anode / anode, Θ=180°sin Anode / anode, DC Kathode / cathode, Θ=180°sin Kathode / cathode, DC	R_{thJC}	 max. 0,068 max. 0,065 max. 0,113 max. 0,110 max. 0,159 max. 0,156	 °C/W °C/W °C/W °C/W °C/W °C/W
Übergangs- Wärmewiderstand thermal resitance, case to heatsink	Kühlfläche / cooling surface beidseitig / two-sided einseitig / single-sided	R_{thCK}	 max. 0,015 max. 0,030	 °C/W °C/W
Höchstzulässige Sperrschichttemperatur max. junction temperature		$T_{vj\,max}$	125	°C
Betriebstemperatur operating temperature		$T_{c\,op}$	-40...125	°C
Lagertemperatur storage temperature		T_{stg}	-40...150	°C

Mechanische Eigenschaften / Mechanical properties

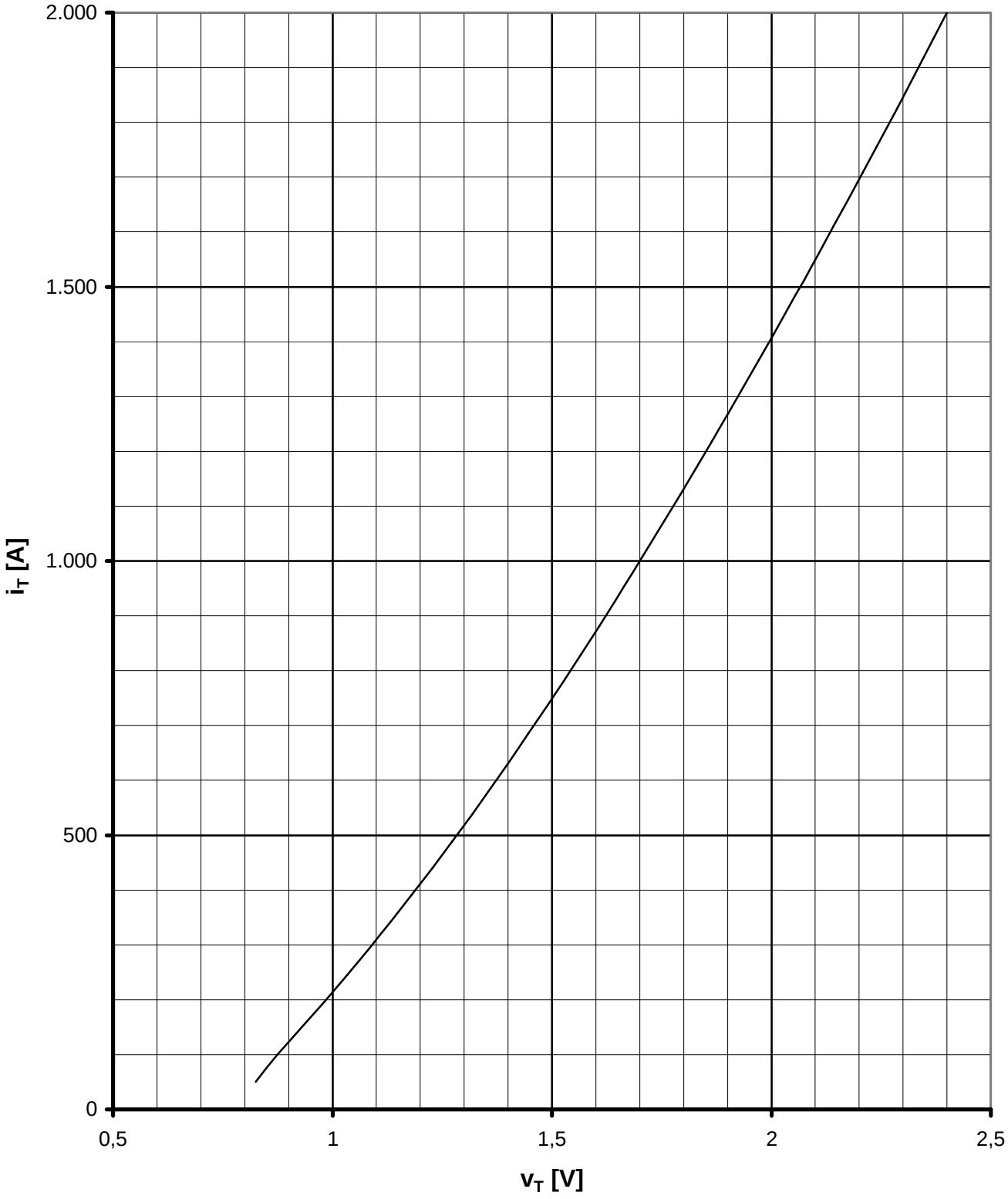
Gehäuse, siehe Anlage case, see appendix			Seite 3 page 3	
Si-Element mit Druckkontakt, Amplifying-Gate Si-pellet with pressure contact, amplifying gate				
Anpreßkraft clamping force		F	4 ...8	kN
Gewicht weight		G	typ. 70	g
Kriechstrecke creepage distance			17	mm
Feuchteklasse humidity classification	DIN 40040		C	
Schwingfestigkeit vibration resistance	f = 50Hz		50	m/s²


ø23
1,1
14
8,5
1,1
4
ø3,5 x 2 deep
on both sides
ø23
C
HK
G
A

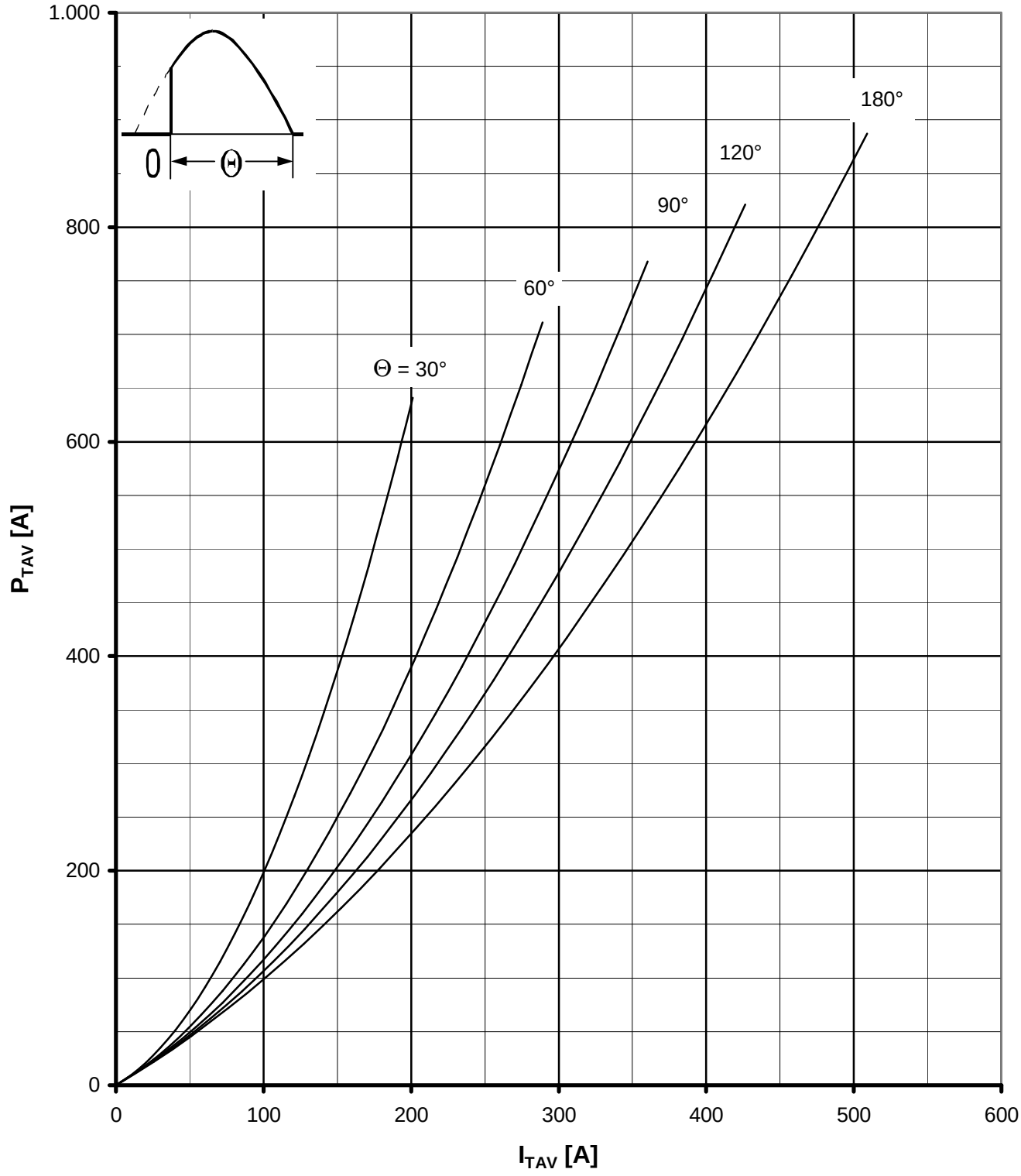

max. 7
HK
ø41
19,5
plug
2,8 x 0,8
G

Kühlung cooling	Analytische Elemente des transienten Wärmewiderstandes Z_{thJC} für DC Analytical ementes of transient thermal impedance Z_{thJC} for DC							
	Pos.n	1	2	3	4	5	6	7
beidseitig	R_{thn} [°C/W]	0,00832	0,0151	0,0181	0,0207	0,00286		
two-sided	τ_n [s]	0,000826	0,0166	0,0808	0,359	1,957		
anodenseitig	R_{thn} [°C/W]	0,00961	0,00543	0,0209	0,0142	0,0271	0,0328	
anode-sided	τ_n [s]	0,00104	0,0133	0,0364	0,23	1,52	10,5	
kathodenseitig	R_{thn} [°C/W]	0,0098	0,0186	0,0157	0,0617	0,0502		
cathode-sided	τ_n [s]	0,00106	0,227	0,0994	2,04	10,2		

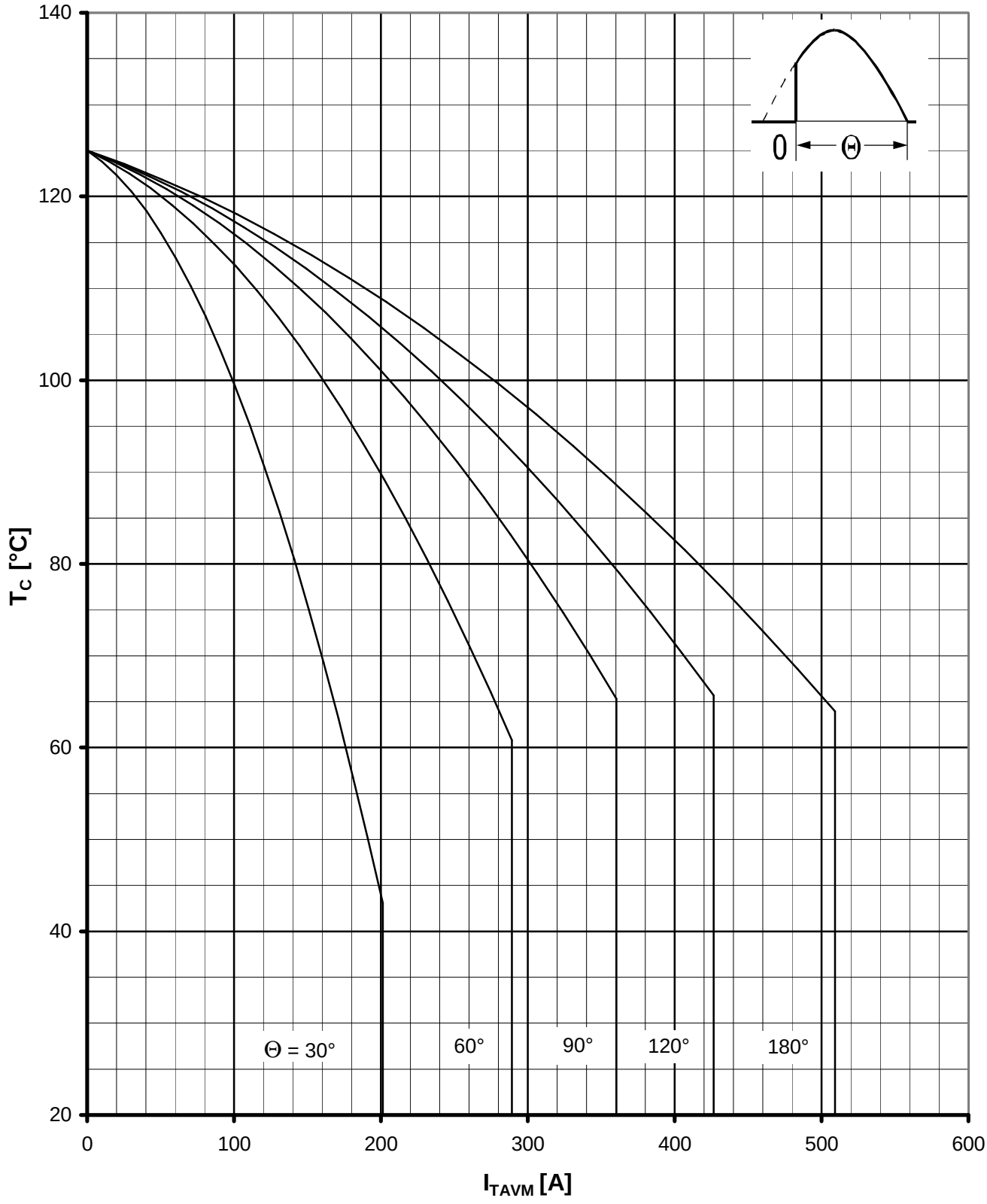
Analytische Funktion / analytical function : $Z_{thJC} = \sum_{n=1}^{n_{max}} R_{thn} (1 - EXP (- t / \tau_n))$



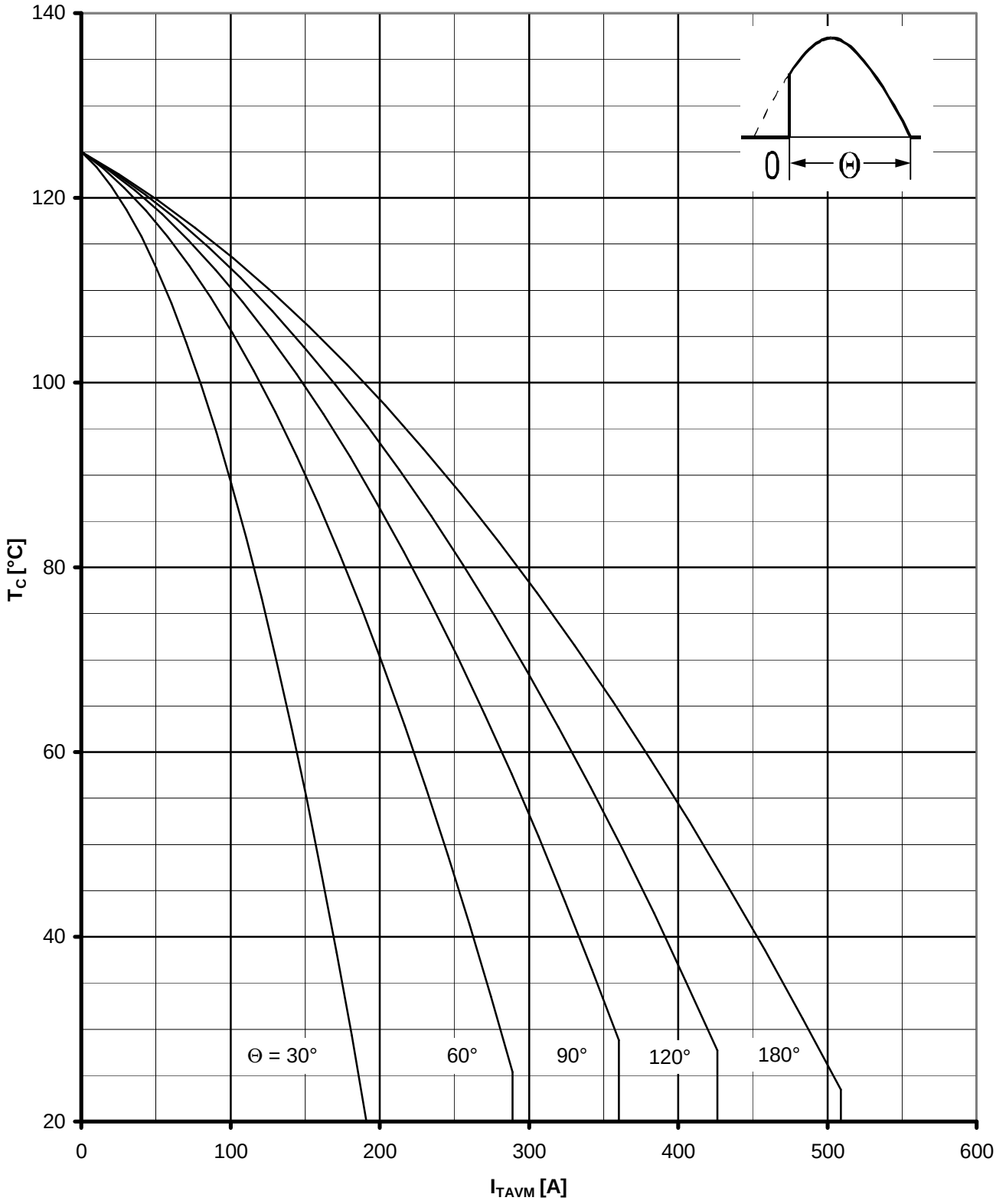
Grenzdurchlaßkennlinie / Limiting 0n-state characteristic $i_T = f(v_T)$
$T_{vj} = T_{vj}$ max



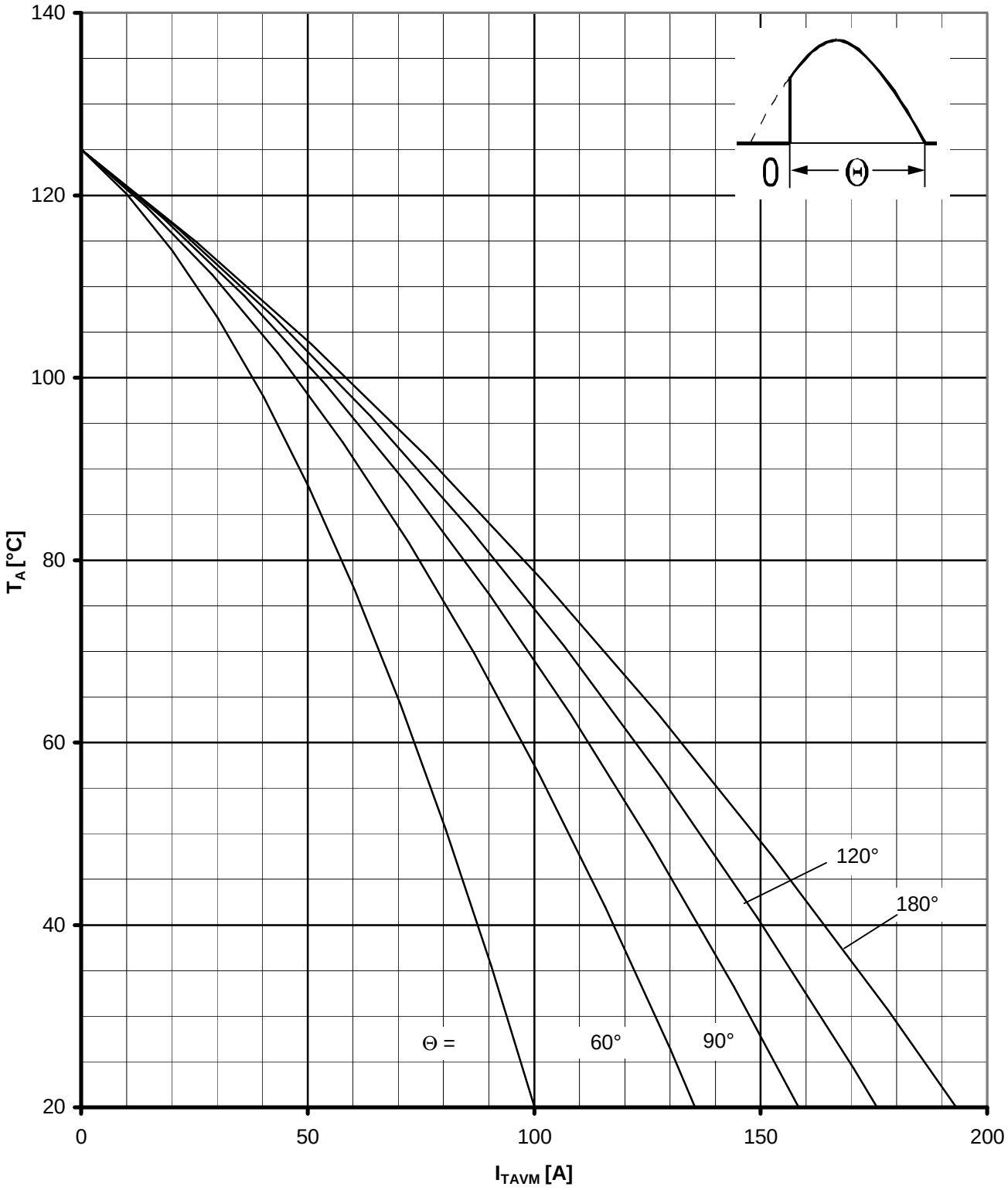
Durchlaßverlustleistung / On-state power loss $P_{TAV} = f(I_{TAV})$
Parameter: Stromflußwinkel Θ / current conduction angle Θ



Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature $T_C = f(I_{TAVM})$
Beidseitige Kühlung / Two-sided cooling
Parameter: Stromflußwinkel Θ / current conduction angle Θ



Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature $T_C = f(I_{TAVM})$
Anodenseitige Kühlung / anode sided cooling
Parameter: Stromflußwinkel Θ / current conduction angle Θ

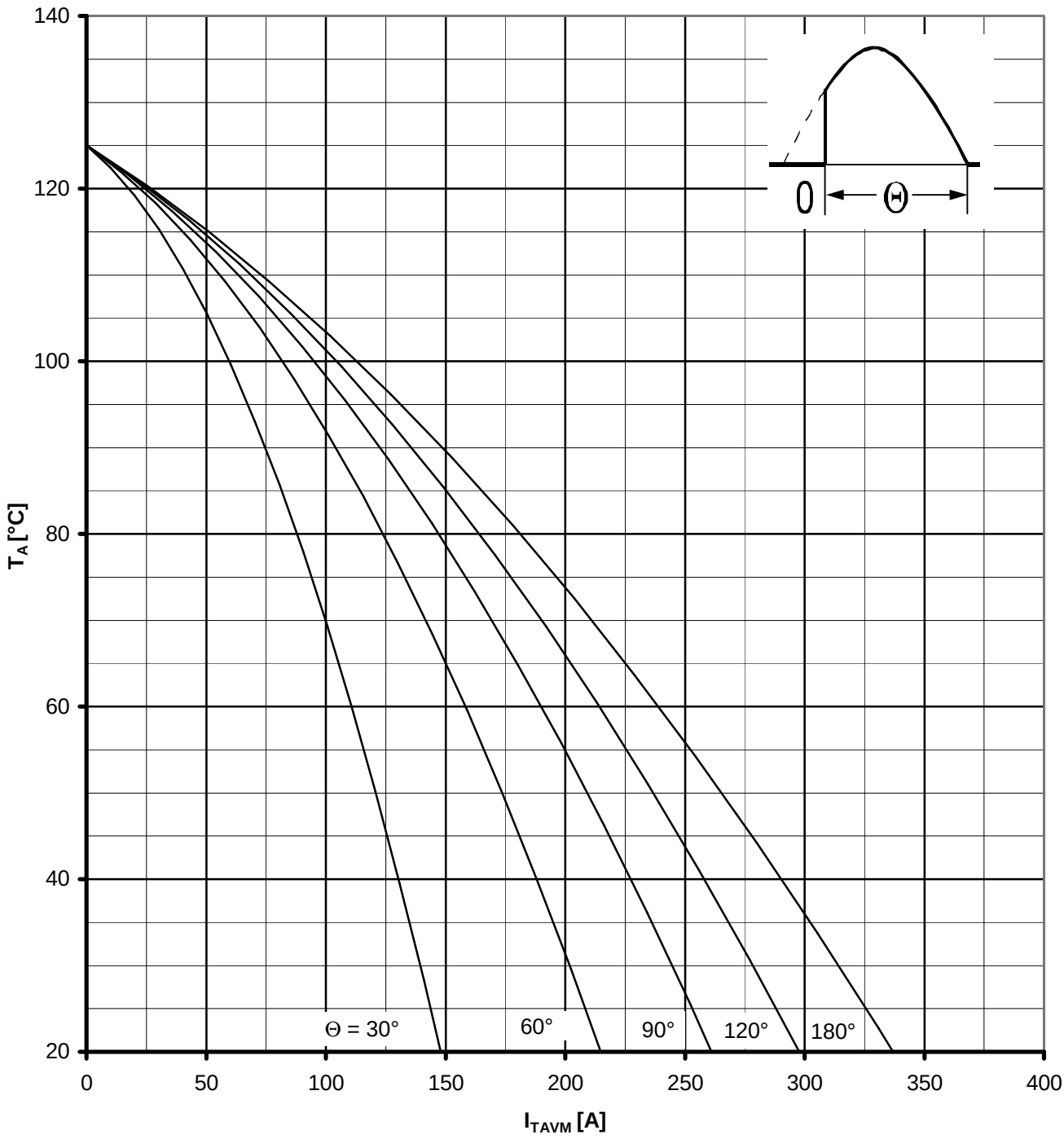


Höchstzulässige Kühlmitteltemperatur / Max. allowable cooling medium temperature $T_A = f(I_{TAVM})$

Luftselbstkühlung / Natural air-cooling

Kühlkörper/Heatsink. K0.36S

Parameter: Stromflußwinkel Θ / current conduction angle Θ

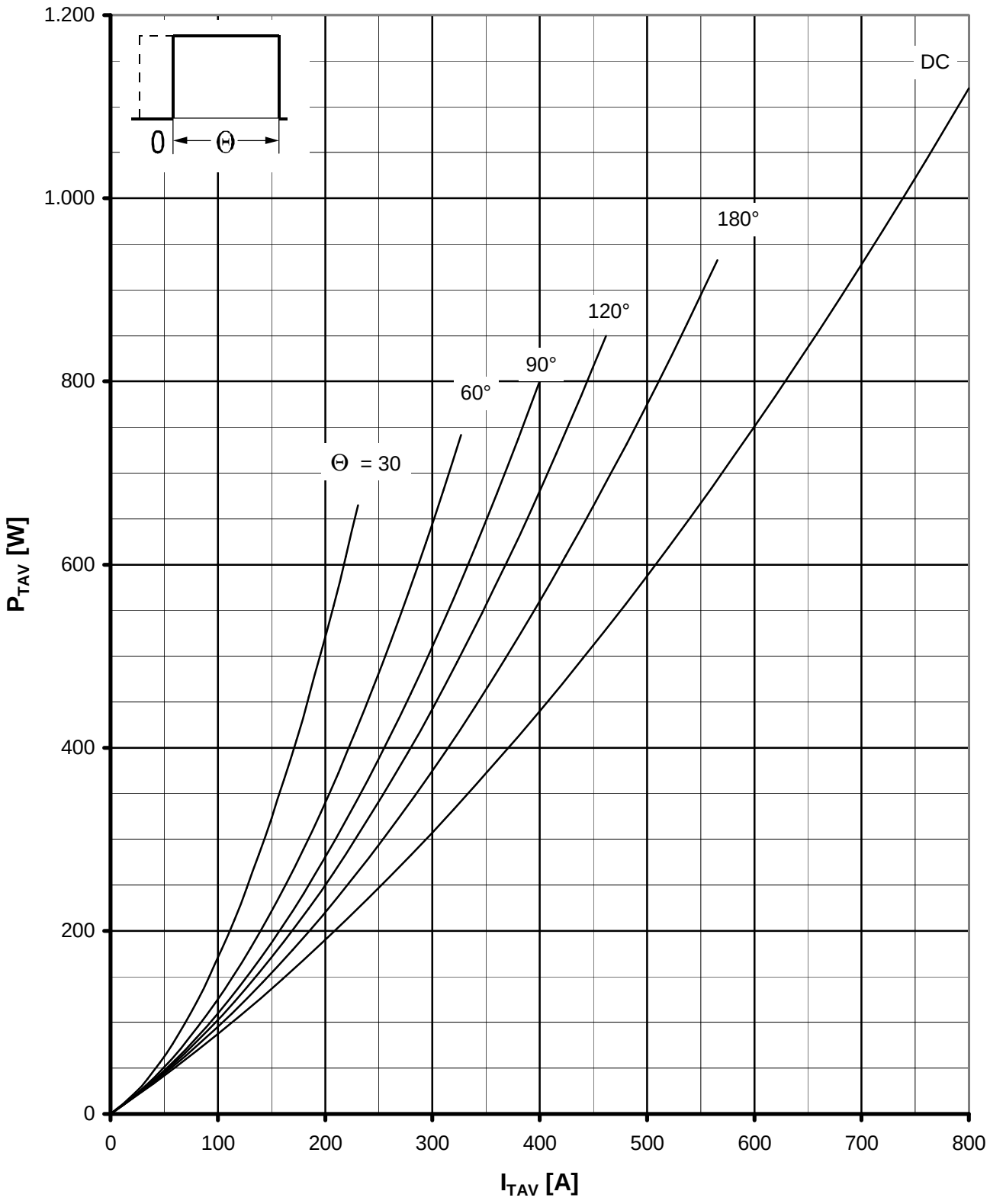


Höchstzulässige Kühlmitteltemperatur / Max. allowable cooling medium temperature $T_A = f(I_{TAVM})$

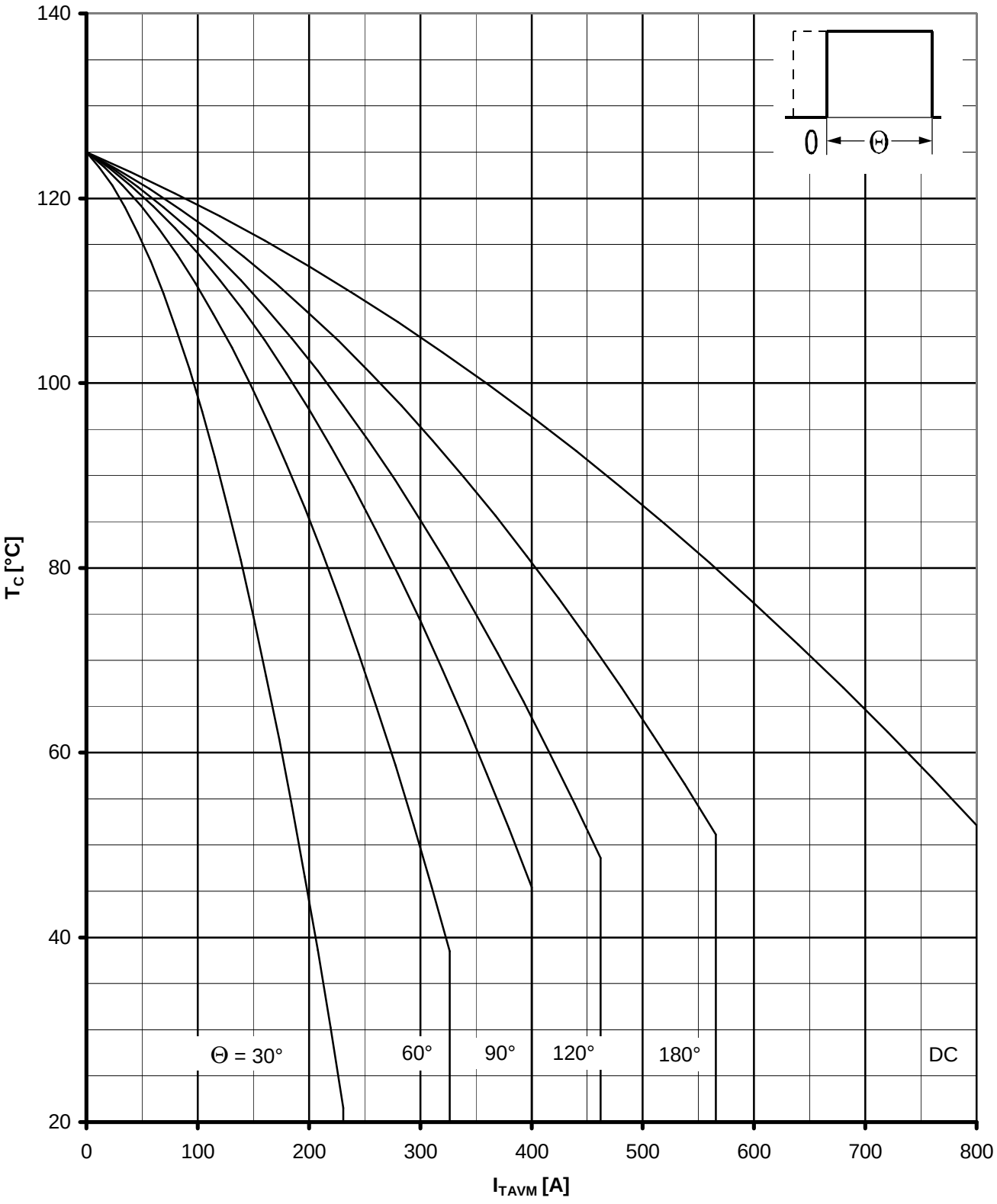
Verstärkte Luftkühlung / Forced air-cooling

Kühlkörper/Heatsink. K0.12F, T_A = 35 °C, V_L = 50 l/s

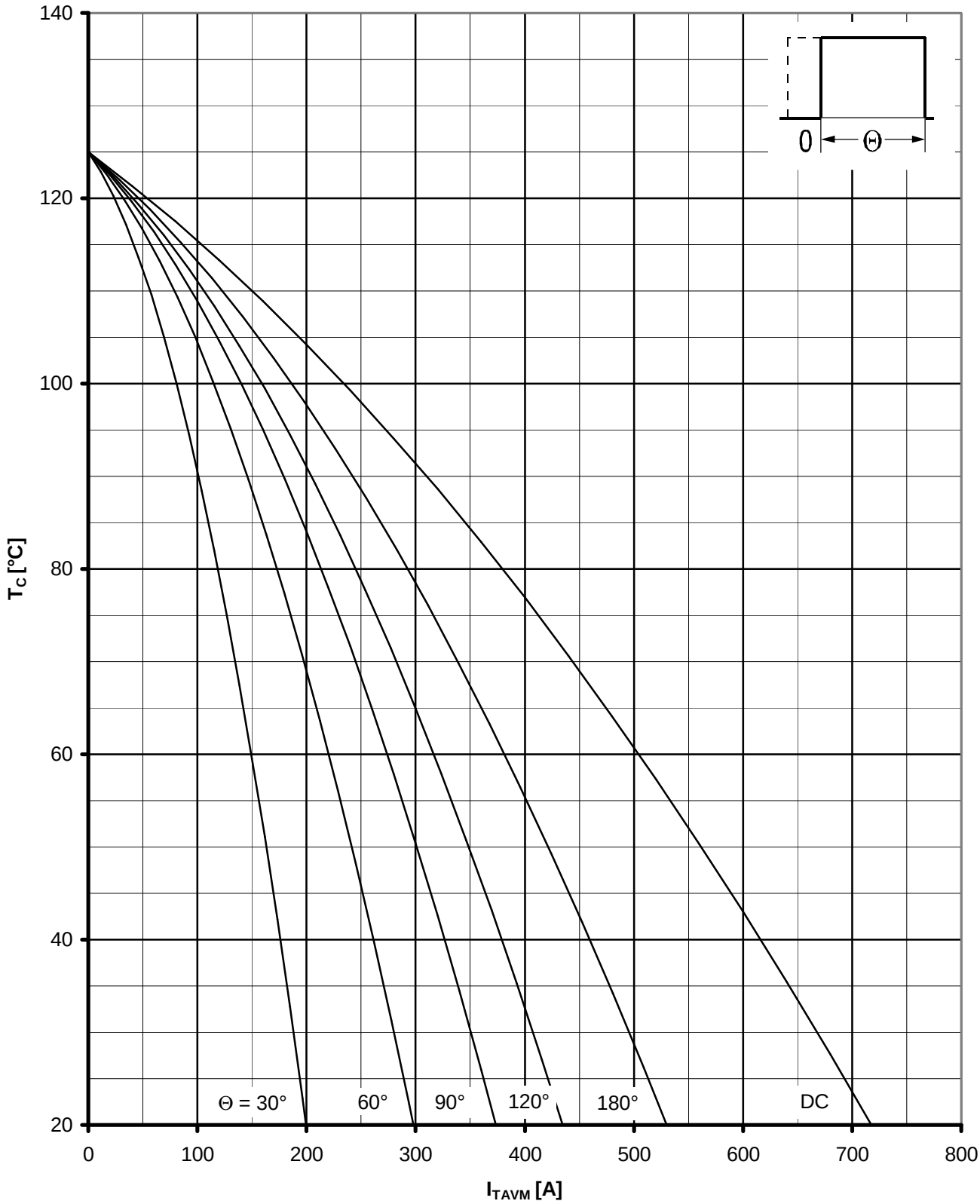
Parameter: Stromflußwinkel Θ / current conduction angle Θ



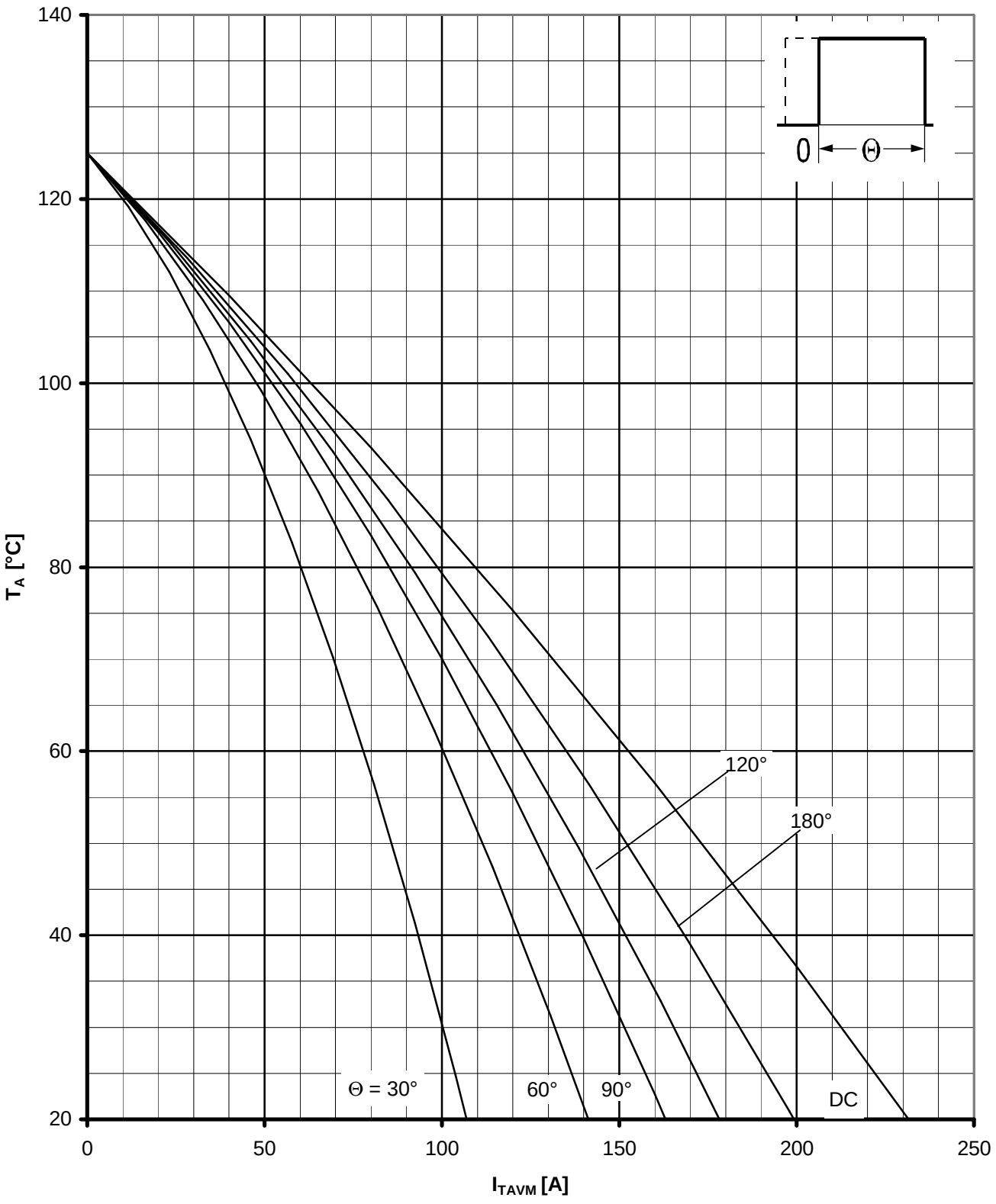
Durchlaßverlustleistung / On-state power loss $P_{TAV} = f(I_{TAV})$
Parameter: Stromflußwinkel Θ / current conduction angle Θ



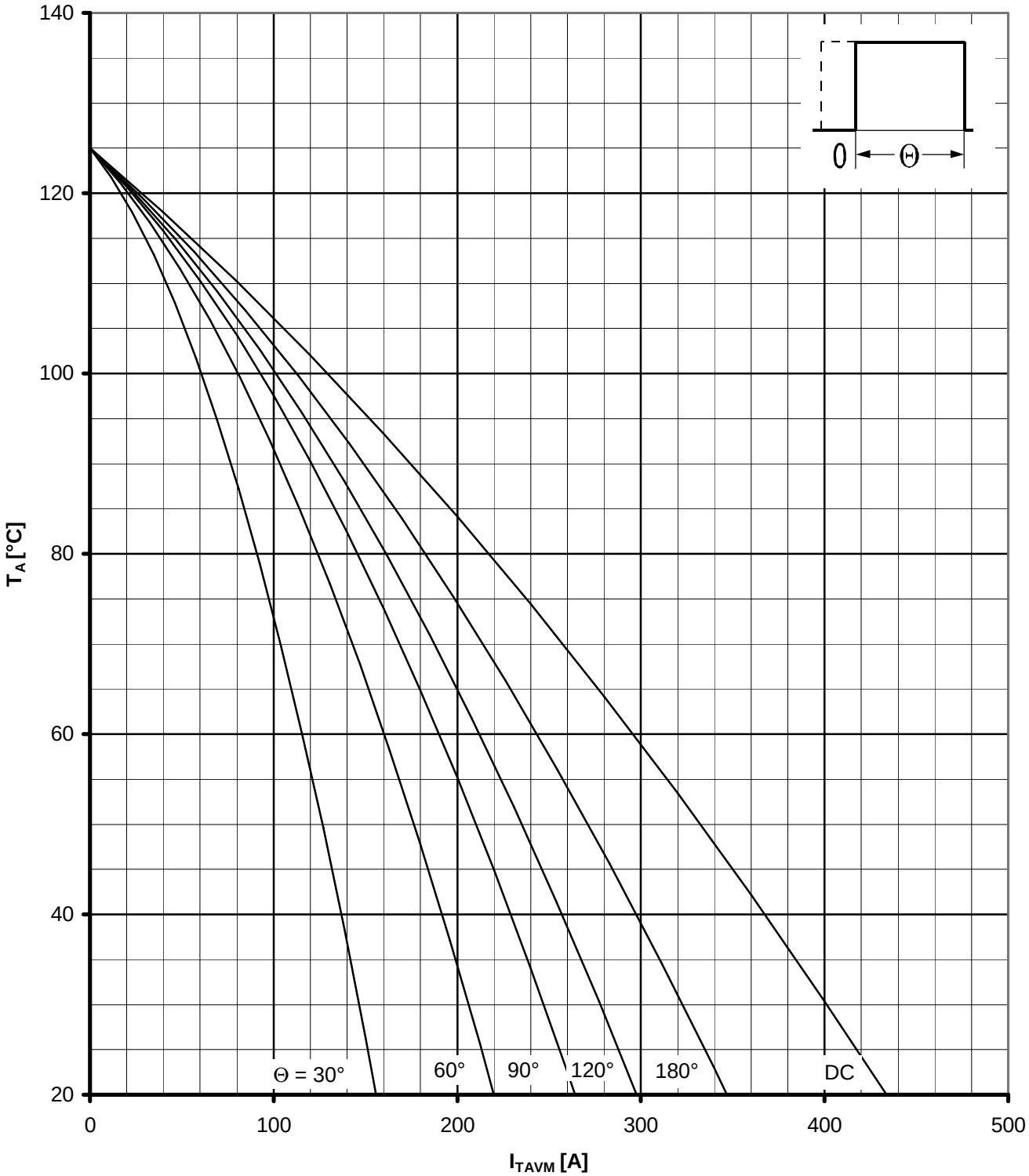
Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature $T_C = f(I_{TAVM})$
Beidseitige Kühlung / Two-sided cooling
Parameter: Stromflußwinkel Θ / current conduction angle Θ



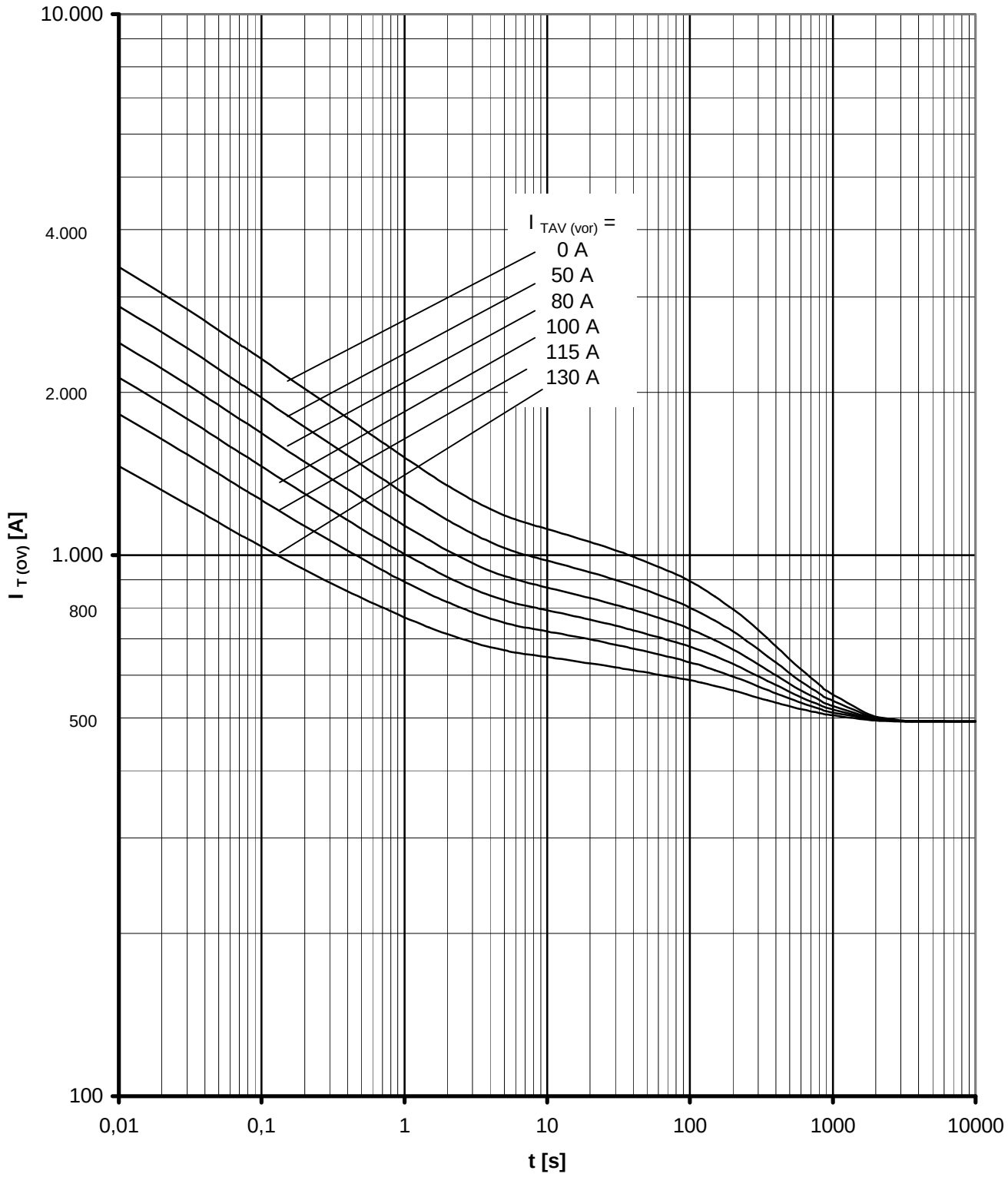
Höchstzulässige Gehäusetemperatur / Maximum allowable case temperature $T_C = f(I_{TAVM})$
Anodenseitige Kühlung / anode sided cooling
Parameter: Stromflußwinkel Θ / current conduction angle Θ



Höchstzulässige Kühlmitteltemperatur / Max. allowable cooling medium temperature $T_A = f(I_{TAVM})$
Luftselbstkühlung / Natural air-cooling
Kühlkörper/Heatsink. K0.36S
Parameter: Stromflußwinkel Θ / current conduction angle Θ

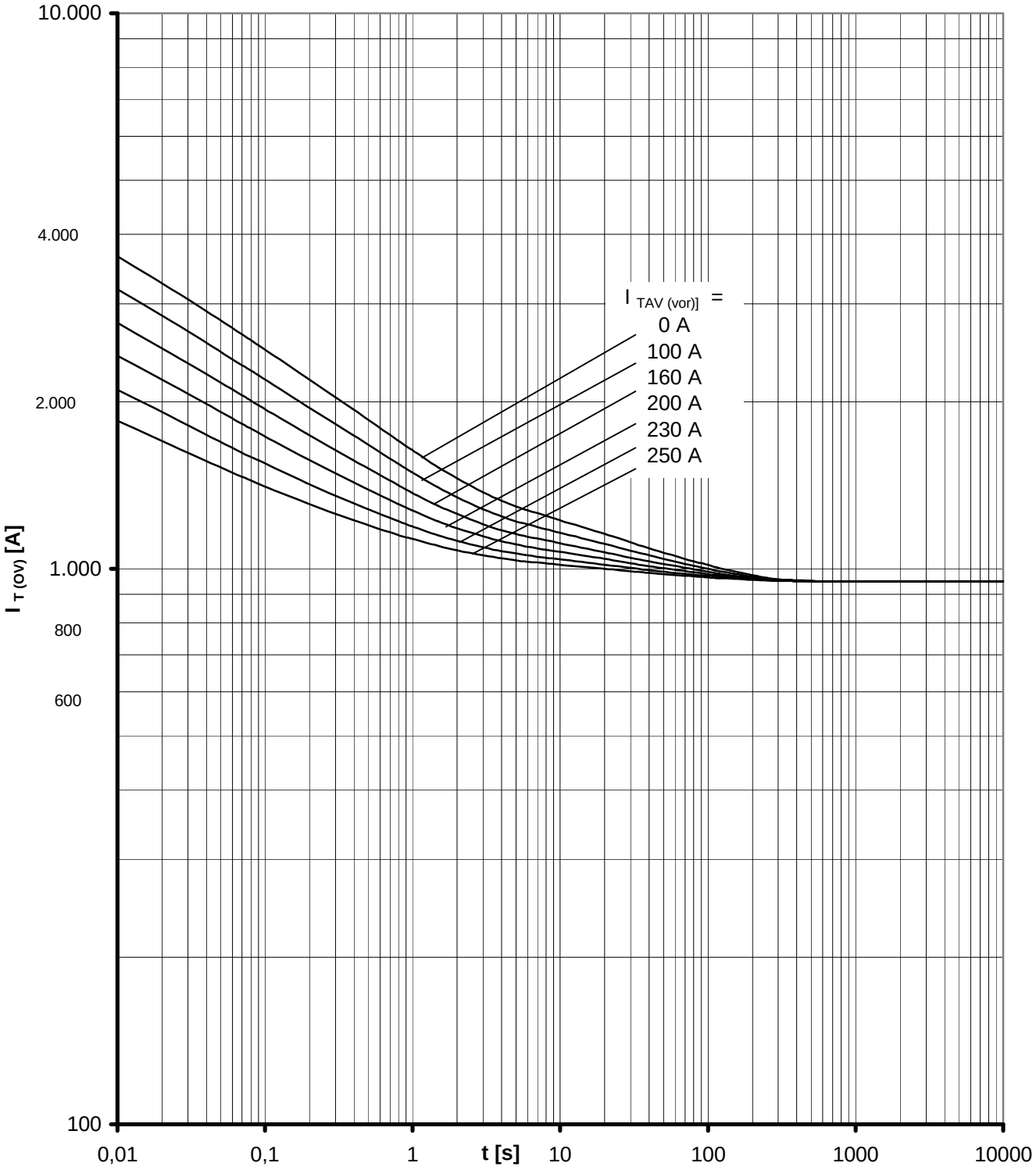


Höchstzulässige Kühlmitteltemperatur / Max. allowable cooling medium temperature $T_A = f(I_{TAVM})$
Verstärkte Luftkühlung / Forced air-cooling
Kühlkörper/Heatsink. K0.05F, V_L = 50 l/s
Parameter: Stromflußwinkel Θ / current conduction angle Θ



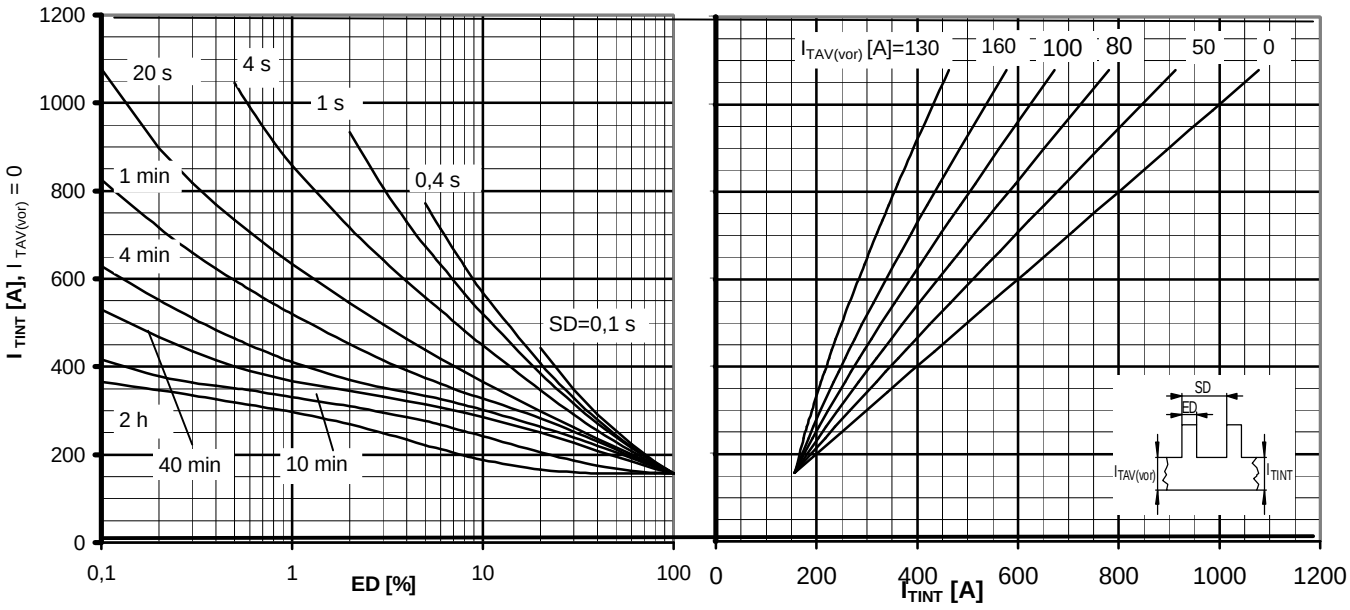
Überstrom / Overload on-state current $I_{T(OV)} = f(t)$

Beidseitige Luftselbstkühlung / Two-sided natural cooling K0.35S
T_A = 45°C
Parameter: Vorlaststrom / pre-load current $I_{TAV(vor)}$



Überstrom / Overload on-state current $I_{T(OV)} = f(t)$

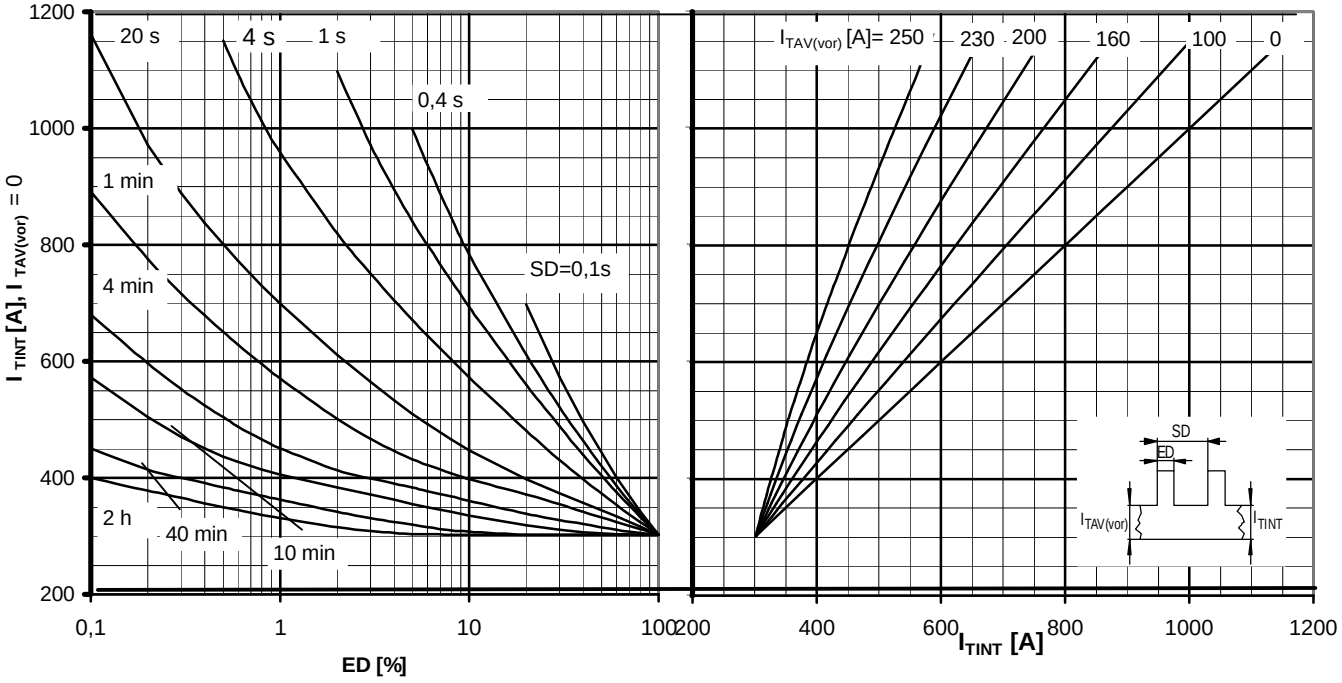
Beidseitige verstärkte Kühlung / forced two-sided cooling K 0.12F
T_A = 35°C, V_L = 50 l/s
Parameter: Vorlaststrom / pre-load current $I_{TAV(vor)}$



Höchstzul. Durchlaßstrom bei Ausetzbetrieb / Max. allowable on-state current
during intermittent operation I_{TINT} = f(ED)

Beidseitig Luftselbstkühlung / two-sided natural cooling K 0.36S
T_A = 45 °C

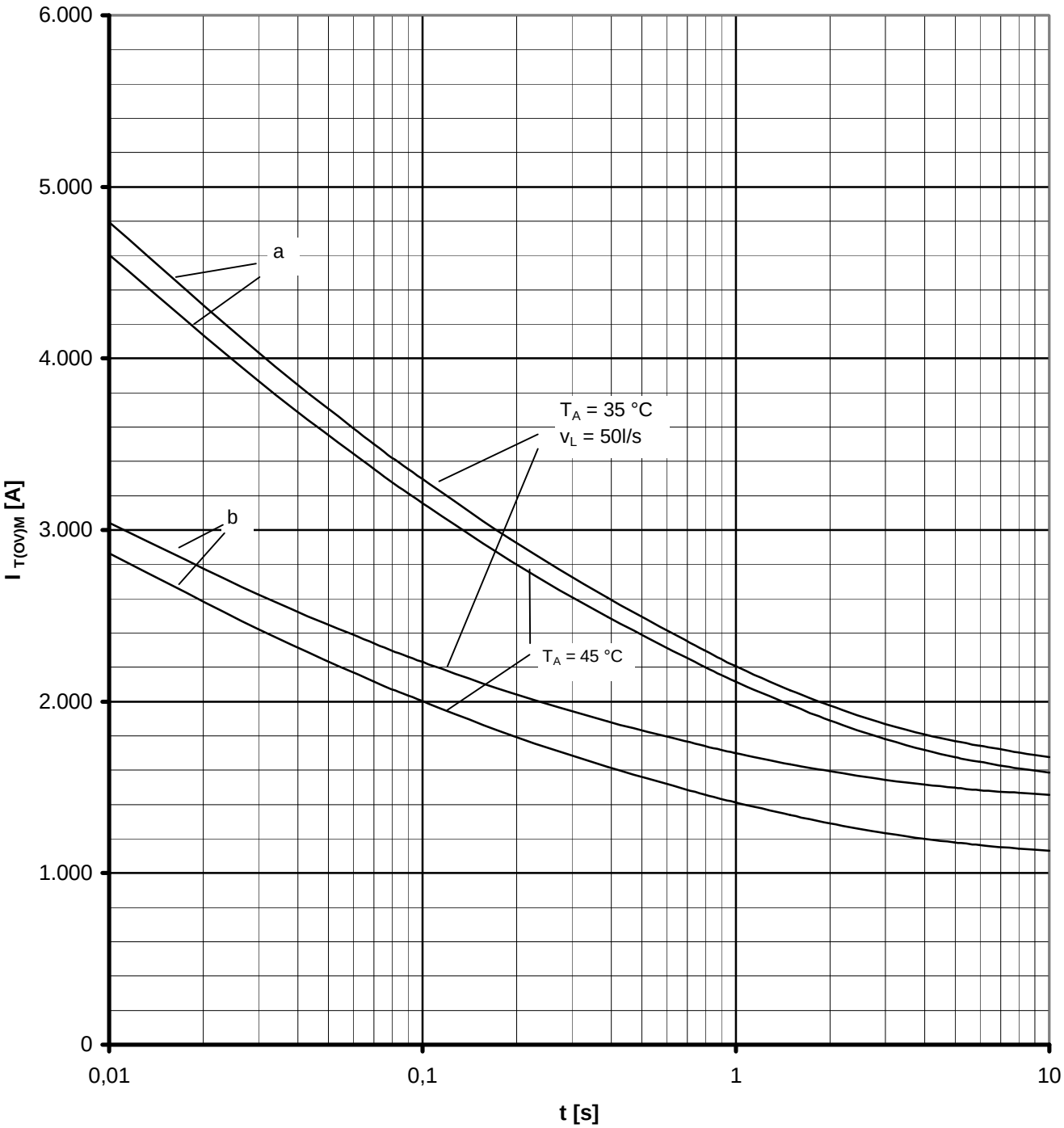
Parameter: Vorlaststrom / pre-load current $I_{TAV(vor)}$, Spieldauer / cycle duration SD



Höchstzul. Durchlaßstrom bei Ausetzbetrieb / Max. allowable on-state current
during intermittent operation I_{TINT} = f(ED)

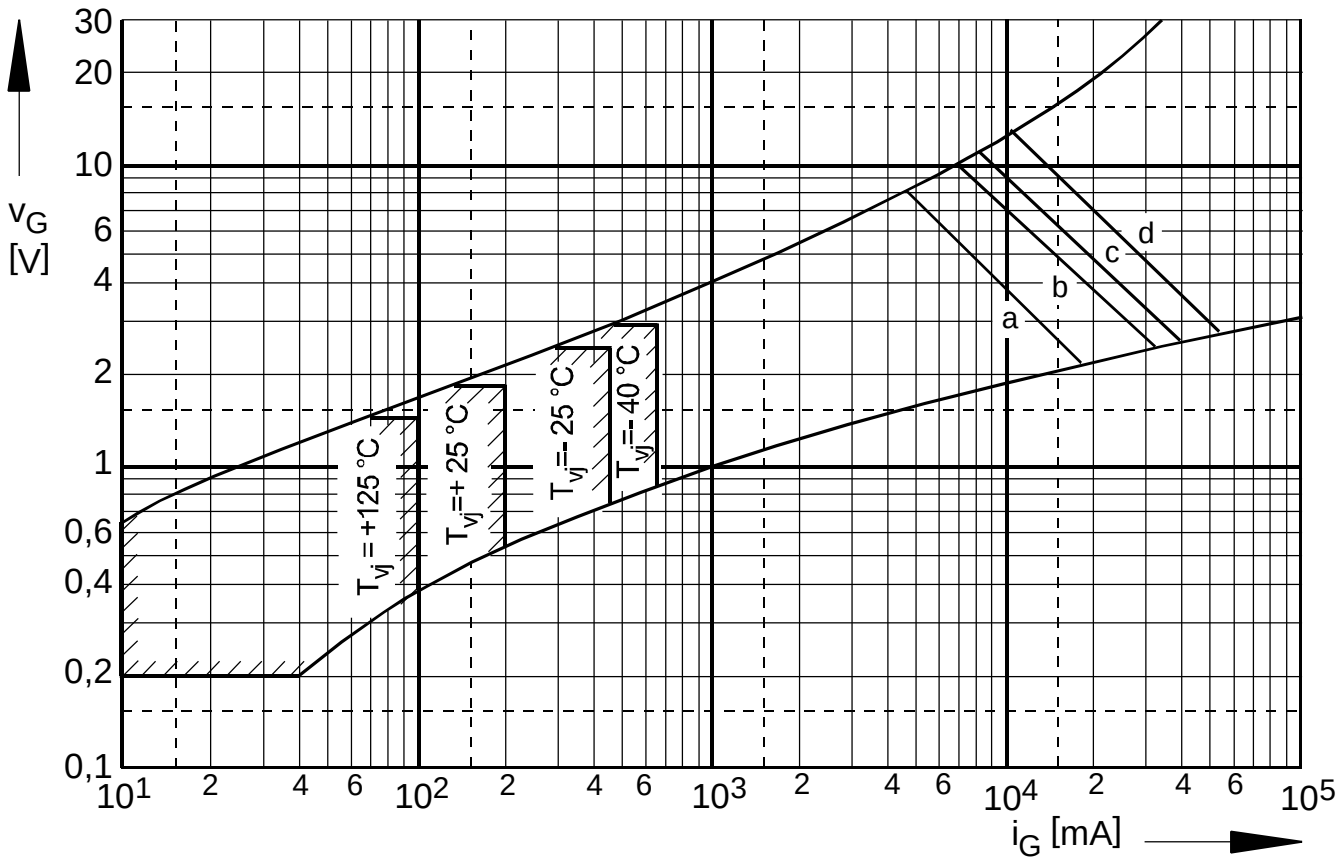
Beidseitig verstärkte Kühlung / forced two-sided cooling K 0.05F
T_A = 35 °C, V_L = 50 l/s

Parameter: Vorlaststrom / pre-load current ITAV(vor) , Spieldauer / cycle duration SD



Grenzstrom / Max. overload on-state current $I_{T(OV)M} = f(t)$, $v_{RM} = 0{,}8\ V_{RRM}$

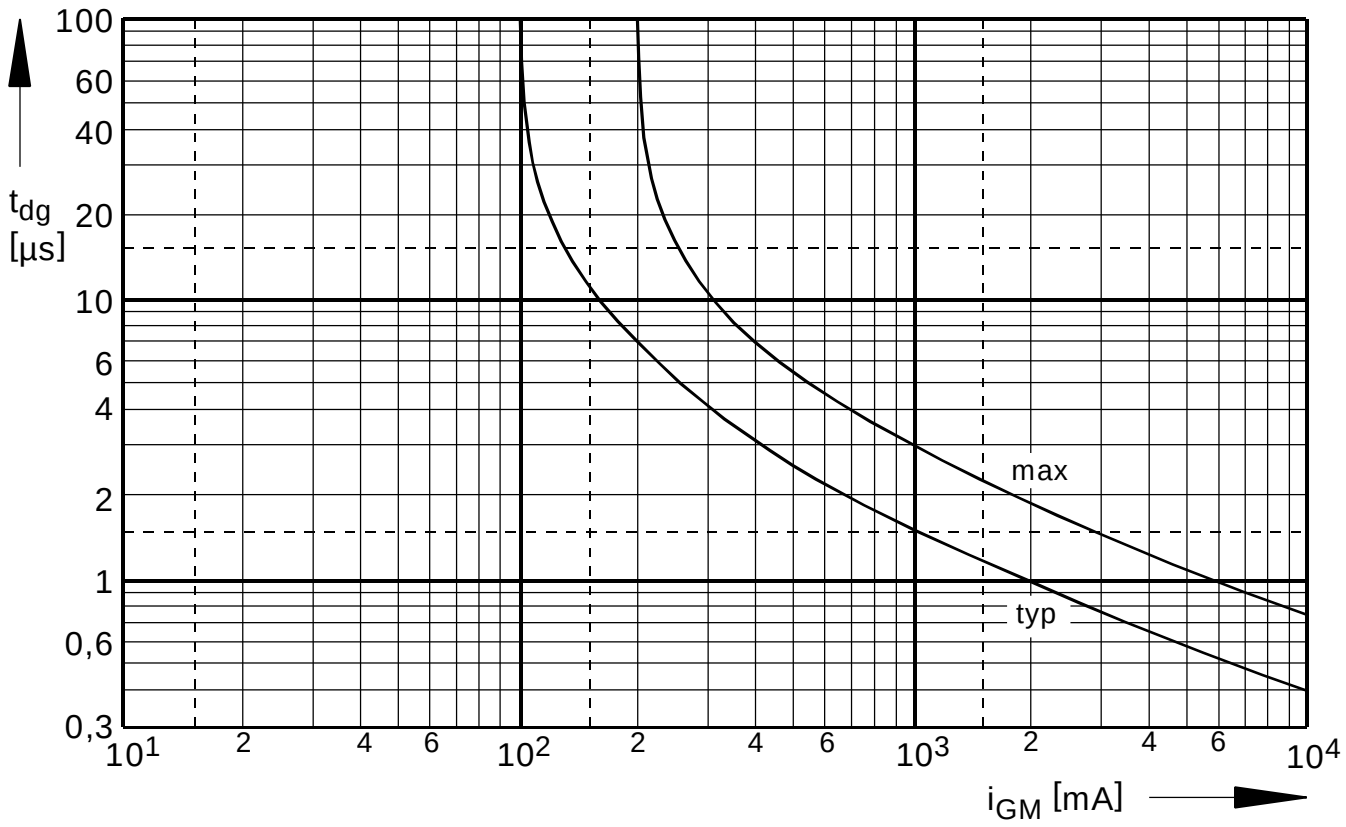
Beidseitige Kühlung / Two-sided cooling
Kühlkörper / Heatsink:K 0.36S, K 0.05F
Belastung aus / Surge current occurs:
a - Leerlauf / No-load conditions
b - Betrieb mit Dauergrenzstrom / During operation at max. average on-state current I_{TAVM}



Steuercharakteristik $v_G = f(i_G)$ mit Zündbereichen für V_D = 6 V
Gate characteristic $v_G = f(i_G)$ with triggering area for V_D = 6 V

Höchstzulässige Spitzensteuerverlustleistung / Maximum rated peak gate power disspation $P_{GM} = f(t_g)$:

a - 40 W/10ms b - 80 W/1ms c - 100 W/0,5ms d - 150 W/0,1ms

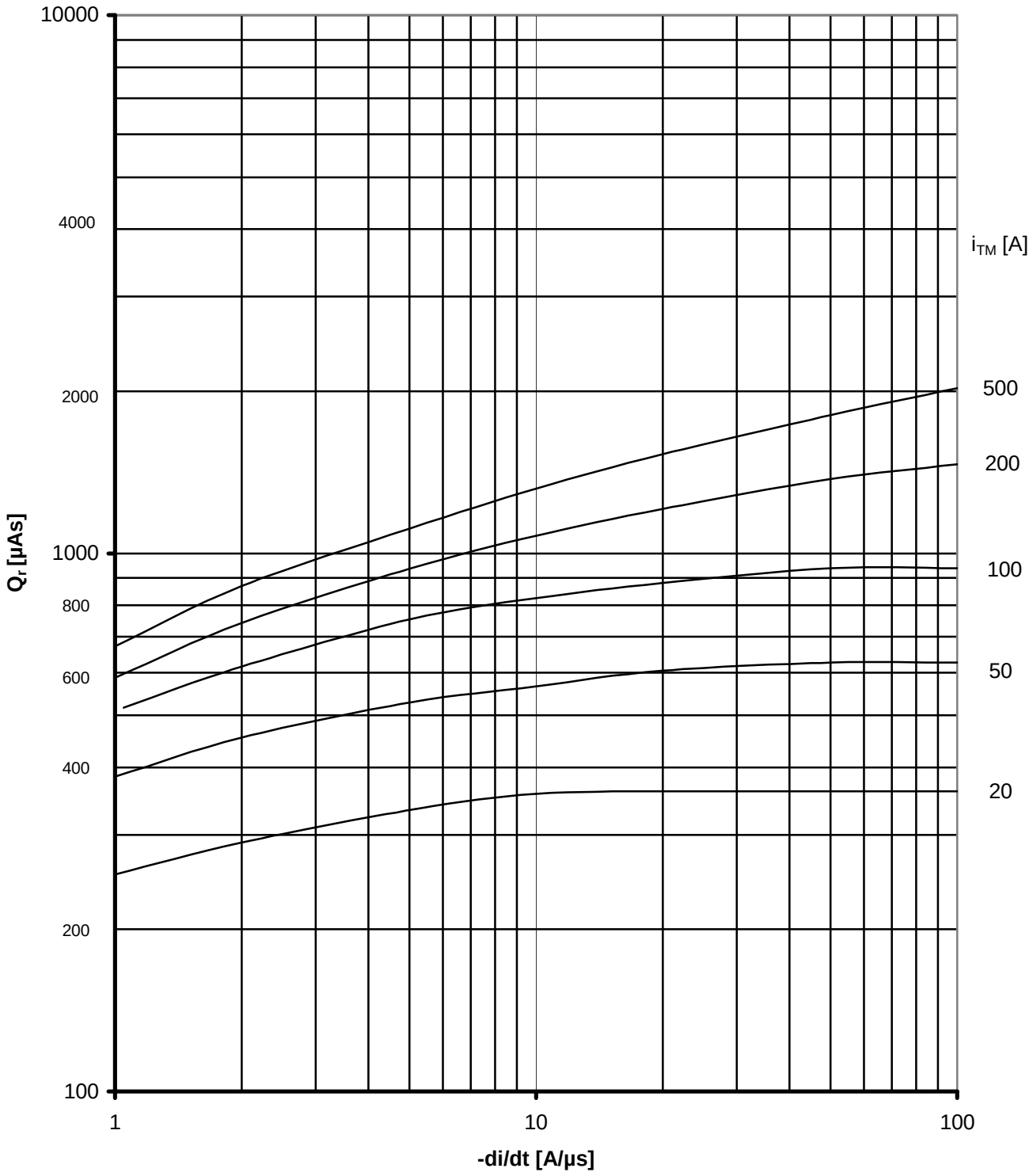


Zündverzug / Gate controlled delay time $t_{gd} = f(i_{GM})$

T_{vj} = 25°C, $di_G/dt = i_{GM}/1\mu s$

a - maximaler Verlauf / limiting characteristic

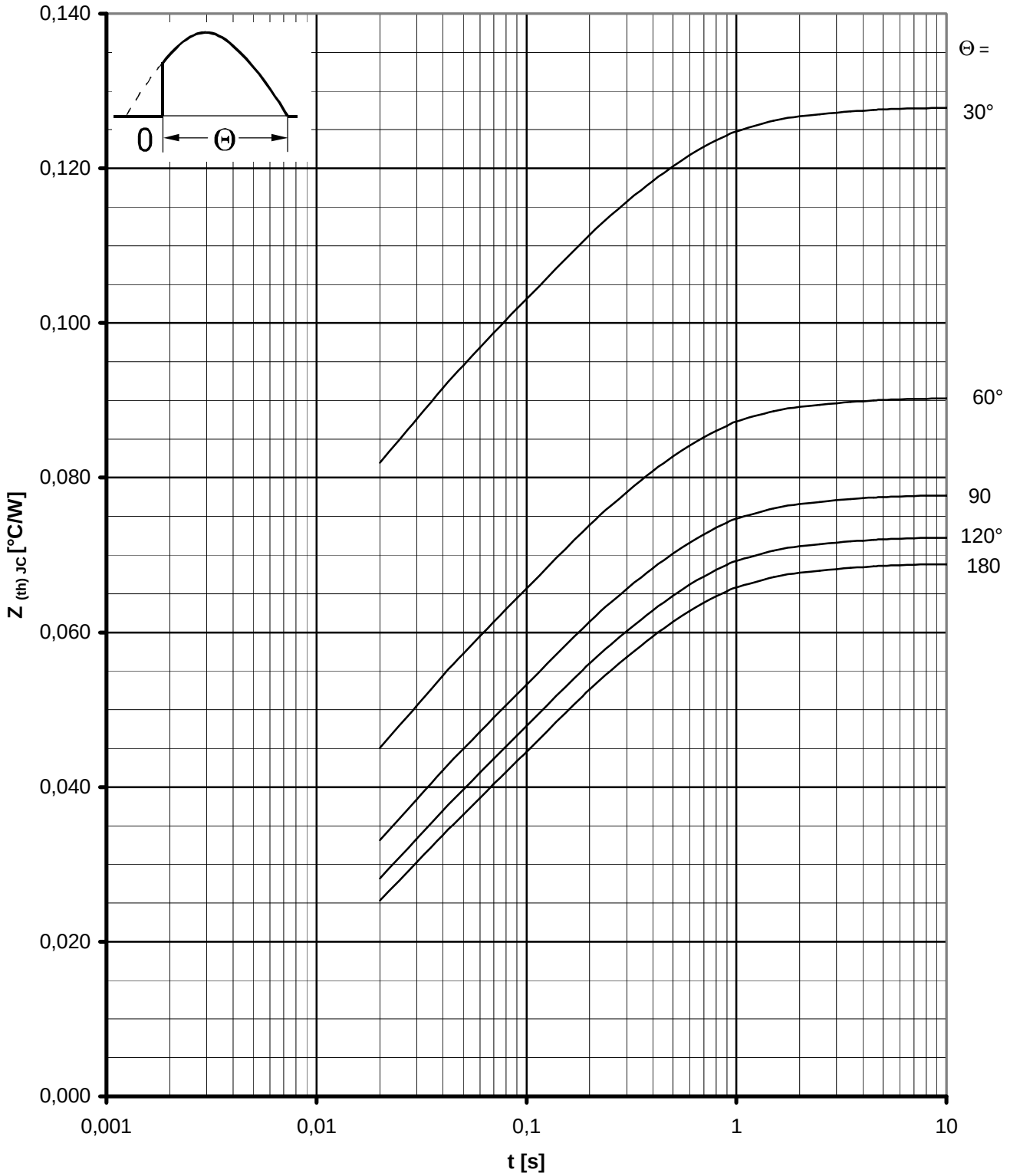
b - typischer Verlauf / typical characteristic



Sperrverzögerungsladung / Recovered charge $Q_r = f(di/dt)$

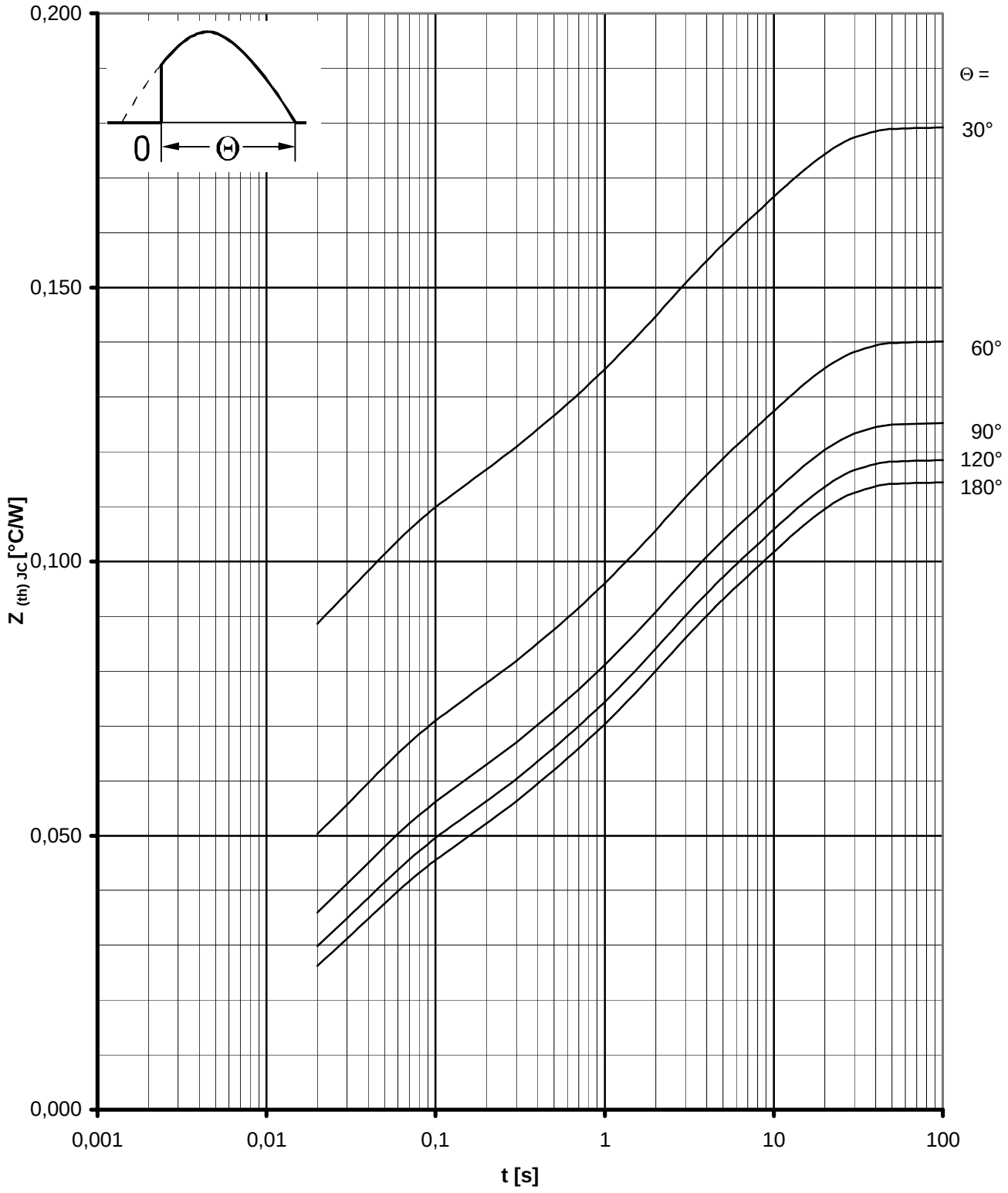
$T_{vj} = T_{vj}$ max, $v_R = 0{,}5\ V_{RRM}$, $v_{RM} = 0{,}8\ V_{RRM}$

Parameter: Durchlaßstrom / On-state current i_{TM}

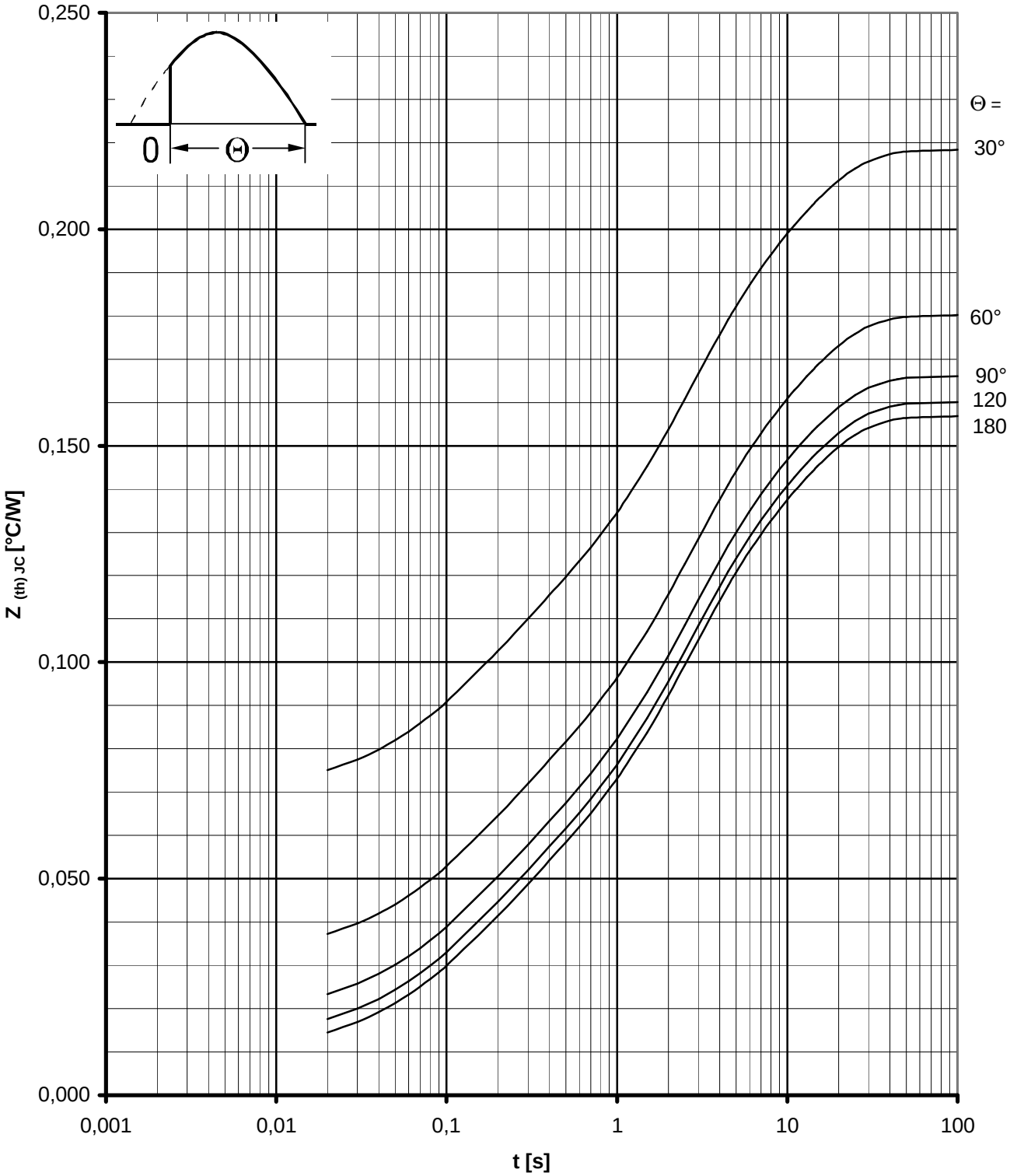


Transienter innerer Wärmewiderstand / Transient thermal impedance $Z_{(th)JC} = f(t)$

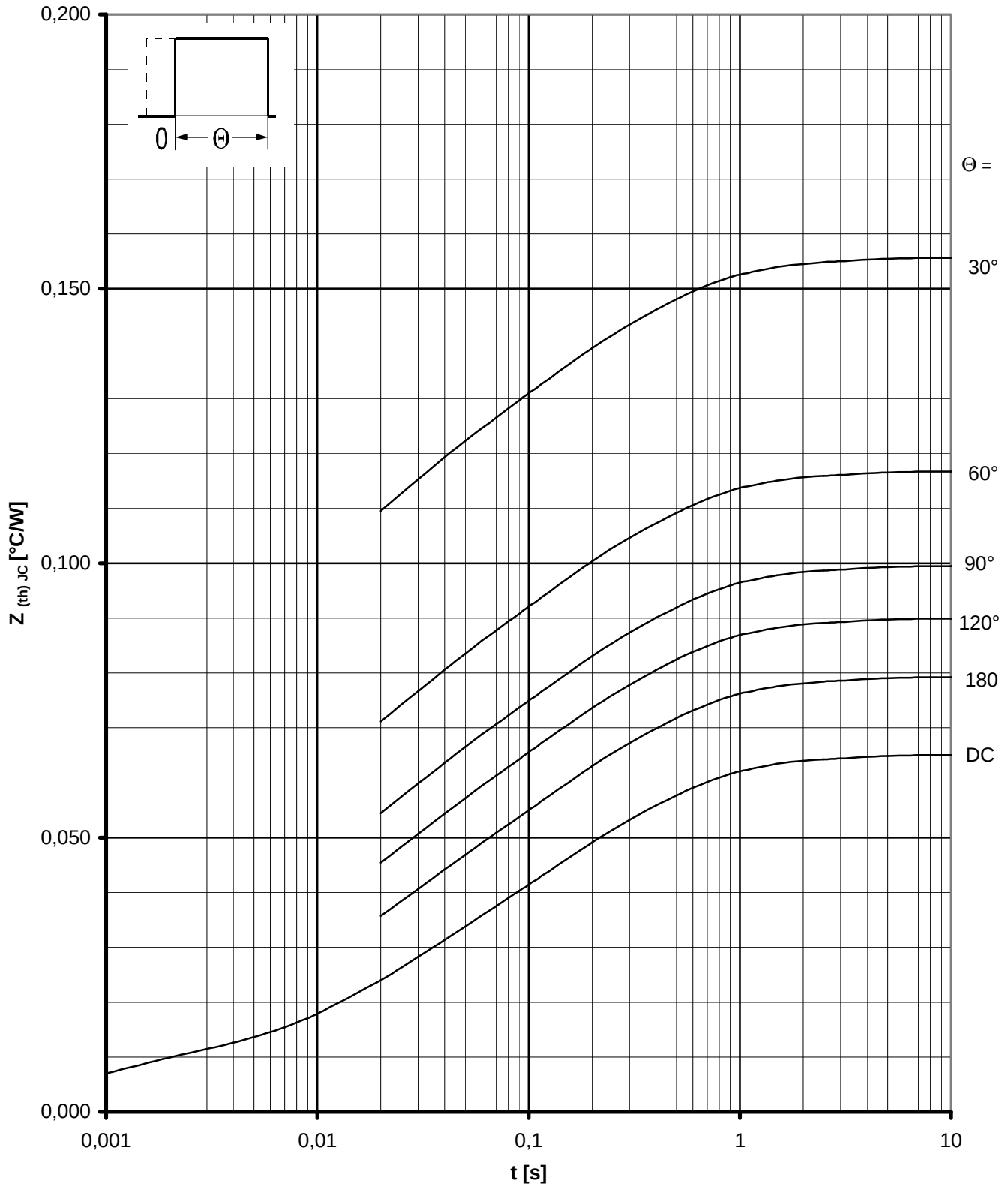
Beidseitige Kühlung /Ttwo-sided cooling
Parameter: Stromflußwinkel Θ / current conduction angle Θ



Transienter innerer Wärmewiderstand / Transient thermal impedance $Z_{(th)JC} = f(t)$
Anodenseitige Kühlung / Anode-sided sided cooling
Parameter: Stromflußwinkel Θ / current conduction angle Θ

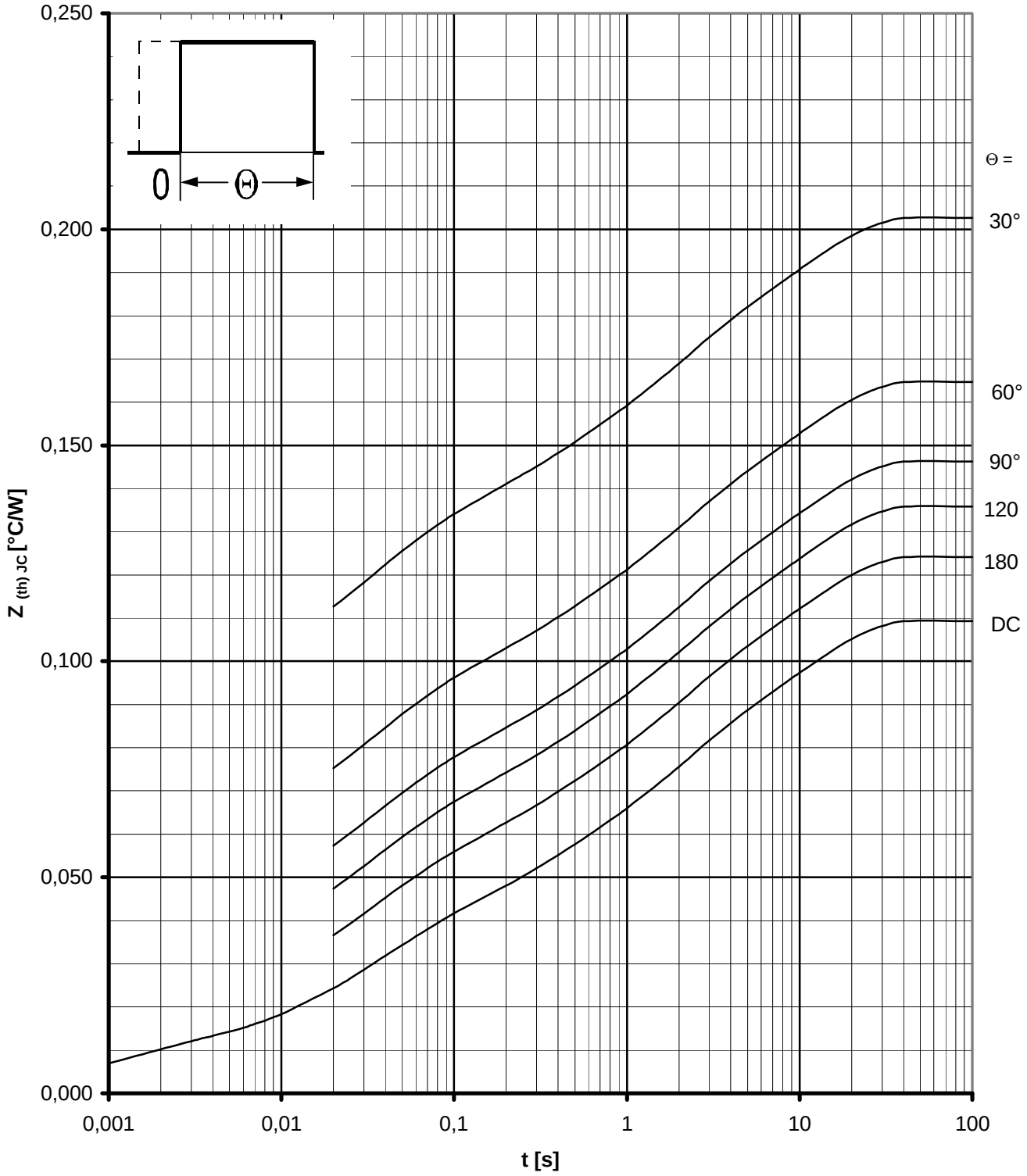


Transienter innerer Wärmewiderstand / Transient thermal impedance $Z_{(th)JC} = f(t)$
Kathodenseitige Kühlung / Cathde-sided cooling
Parameter: Stromflußwinkel Θ / current conduction angle Θ

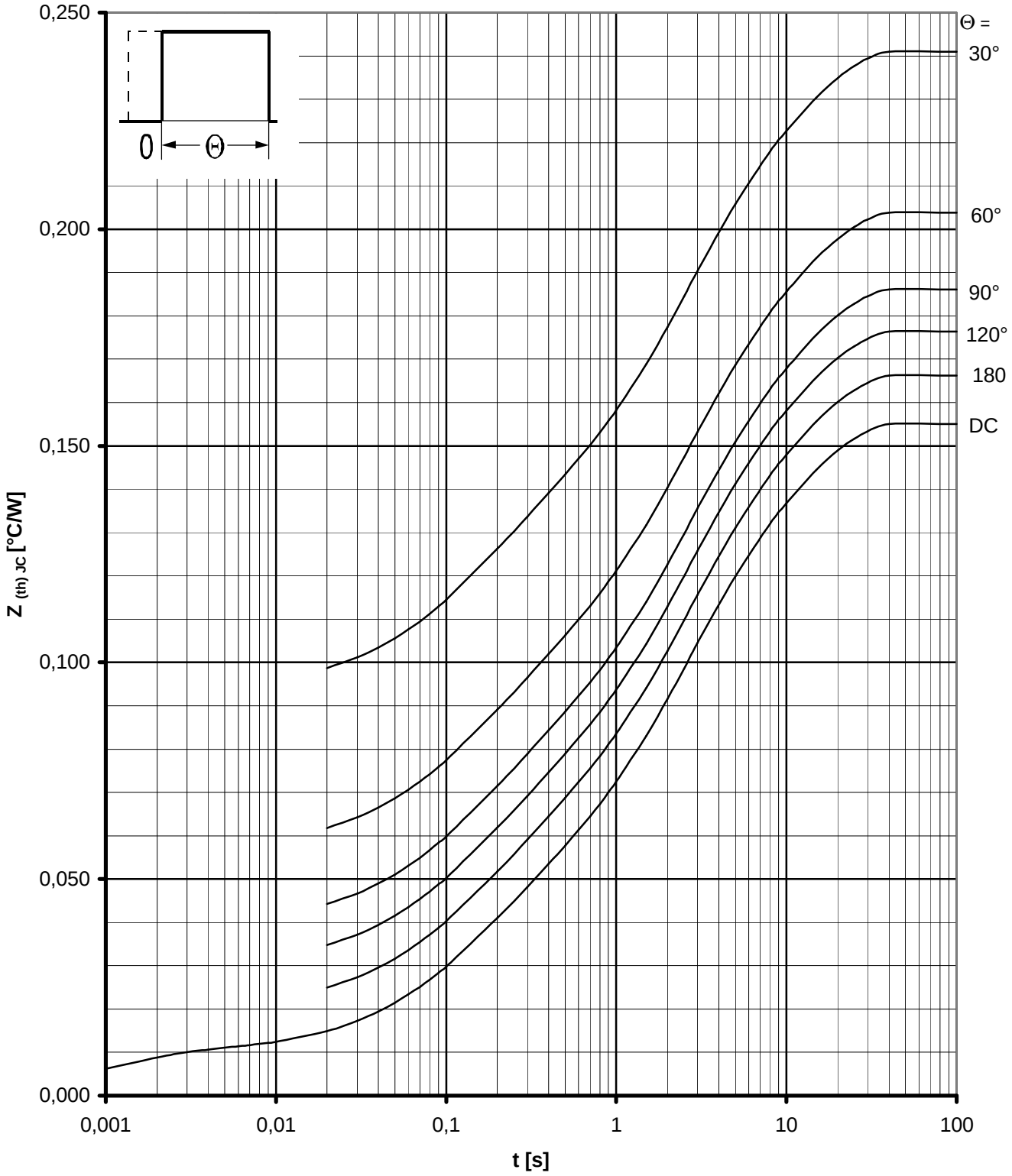


Transienter innerer Wärmewiderstand / Transient thermal impedance $Z_{(th)JC} = f(t)$

Beidseitige Kühlung / Two-sided cooling
Parameter: Stromflußwinkel Θ / current conduction angle Θ



Transienter innerer Wärmewiderstand / Transient thermal impedance $Z_{(th)JC} = f(t)$
Anodenseitige Kühlung / Anode-sided cooling
Parameter: Stromflußwinkel Θ / current conduction angle Θ



Transienter innerer Wärmewiderstand / Transient thermal impedance $Z_{(th)JC} = f(t)$

Kathodenseitige Kühlung / Cathode-sided cooling
Parameter: Stromflußwinkel Θ / current conduction angle Θ